



## UV-TIAMO-BL High Sensitive pre-amplified SiC UV Photodetector



### Properties of the UV-TIAMO-BL

- Broad Band pre-amplified UV photodetector for very low radiation
- Sensitive area  $A = 12,80\text{mm}^2$ ,  $0,22\text{mm}^2$  SiC detector chip
- Applications: flame control and other low radiation measurements
- $1\text{nW/cm}^2$  peak radiation results a voltage of approx. 280 mV

### The UV-TIAMO pre-amplified UV photodetectors

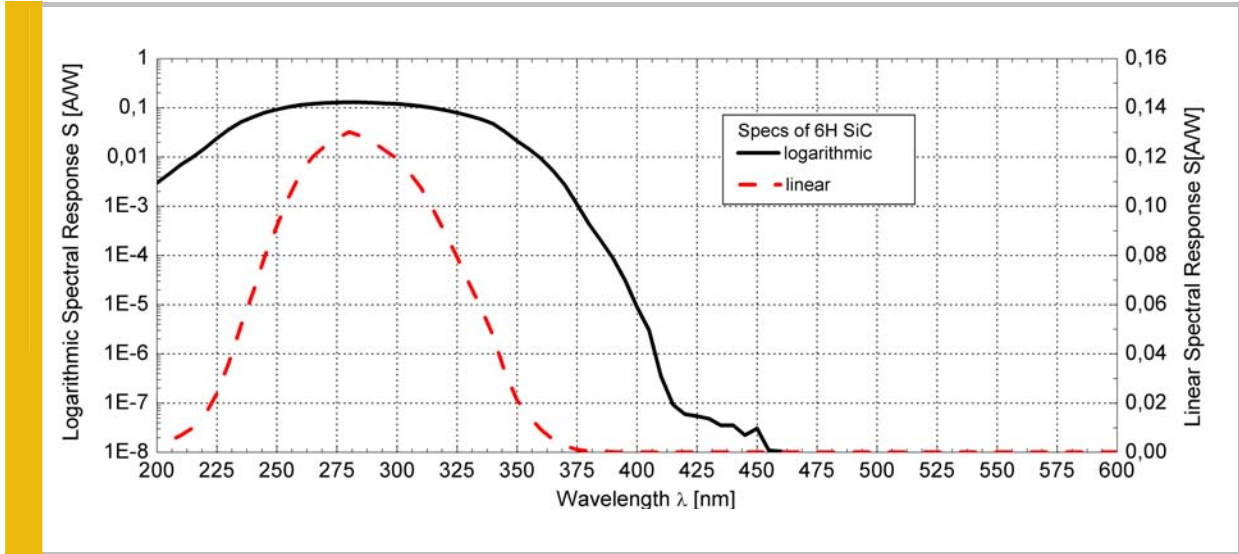
The UV-TIAMO devices are using modern hybride technology to cancel unwanted signal disturbances caused by moisture or electromagnetic radiation. The stable 0...5V output voltage can be directly connected to a SPC controller or a voltage multimeter.

## Specifications

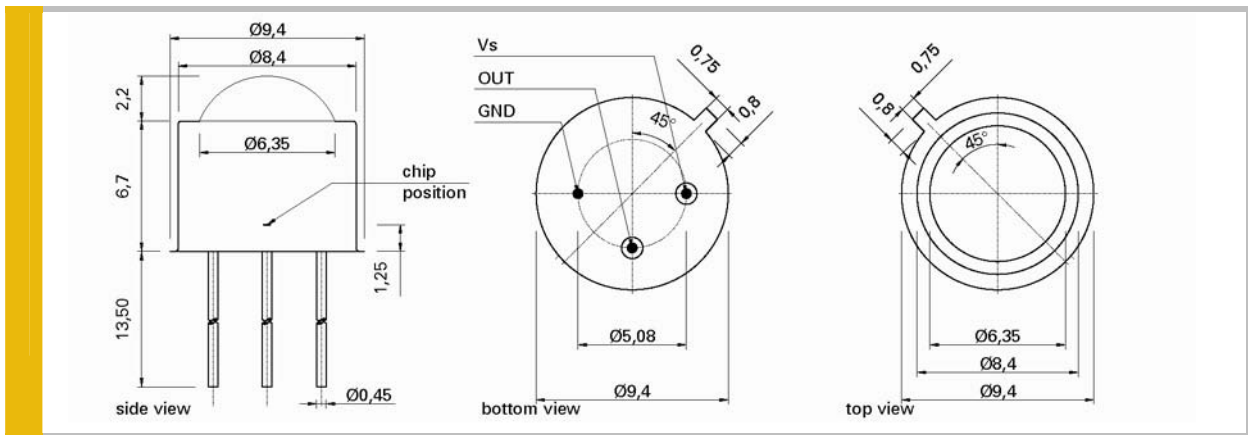
Parameter	Symbol	Value	Unit
<b>Maximum Ratings</b>			
Operating Temperature Range	$T_{opt}$	-25 ... +85	°C
Storage Temperature Range	$T_{stor}$	-40 ... +100	°C
Soldering Temperature (3s)	$T_{sold}$	300	°C
<b>General Characteristics (T=25°C)</b>			
Sensitive area	$A_{sens}$	12,80	mm <sup>2</sup>
Chip area	$A_{chip}$	0,22	mm <sup>2</sup>
Supply voltage	$V_{supply}$	2,5 ... 5,0	V
max. voltage	$V_{max}$	5,5	V
saturation voltage	$V_{sat}$	5,0	V
dark offset voltage	$V_{offset}$	0,5	mV
Temperature coefficient	$T_C$	<-0,3	%/K
Current	$I$	0,8	mA
Bandwidth (-3 dB)	$\theta$	15	Hz
risetime (63%)	$t_{rise}$	10	ms
<b>Spectral Characteristics (T=25°C)</b>			
Sensitivity at peak	$S_{max}$	280	mV/nW/cm <sup>2</sup>
Wavelength of max. spectral sens.	$\lambda_{max}$	280	nm
Sensitivity range ( $S=0,1 \cdot S_{max}$ )	-	210 ... 380	nm
Visible blindness ( $S_{max} / S_{>400nm}$ )	VB	$10^5$	-



## Spectral Response



## Drawing



## Viewing Angle

